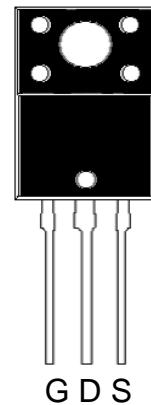


N-Channel Enhancement Mode Power MOSFET

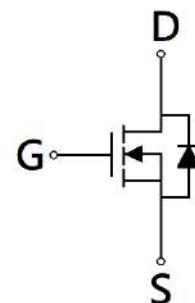
Features:

- Low On Resistance
- Low Gate Charge
- Fast Switching Characteristic

TO-220FP



BV _{DSS}	100V
I _D @V _{GS} =10V, T _C =25°C	25A
I _D @V _{GS} =10V, T _A =25°C	13A
R _{D(S)} (typ.) @ V _{GS} =10V, I _D =10A	8.8mΩ



G : Gate S : Source D : Drain

Ordering Information

Device	Package	Shipping
KE8D5N10RFP	TO-220FP (RoHS compliant)	50 pcs/tube, 20 tubes/box, 5 boxes / carton



Absolute Maximum Ratings ($T_A=25^\circ\text{C}$)

Parameter	Symbol	Limits	Unit
Drain-Source Voltage	V _{DS}	100	V
Gate-Source Voltage	V _{GS}	±20	
Continuous Drain Current @ V _{GS} =10V, T _C =25°C	I _D	25	A
Continuous Drain Current @ V _{GS} =10V, T _C =100°C		16	
Continuous Drain Current @ V _{GS} =10V, T _A =25°C		13	
Continuous Drain Current @ V _{GS} =10V, T _A =70°C		10	
Pulsed Drain Current	I _{DM}	100	
Continuous Body Diode Forward Current @ T _C =25°C	I _S	11	
Avalanche Current @ L=0.1mH	I _{AS}	15	
Avalanche Energy @ L=0.5mH	E _{AS}	36	mJ
Total Power Dissipation	T _C =25°C	*a	W
	T _C =100°C	*a	
	T _A =25°C	*b	
	T _A =70°C	*b	
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-55~+150	°C

Thermal Data

Parameter	Symbol	Steady State	Unit
Thermal Resistance, Junction-to-case	R _{θJC}	9	°C/W
Thermal Resistance, Junction-to-ambient	R _{θJA}	32	

Note:

- *a. The power dissipation P_D is based on T_{J(MAX)}=150°C, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heatsinking is used.
- *b. The value of R_{θJA} is measured with the device mounted on 1 in² FR -4 board with 2 oz. copper, in a still air environment with T_A=25°C. The power dissipation P_D is based on R_{θJA} and the maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.
- *c. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and low duty cycles to keep initial T_J=25°C.



Electrical Characteristics ($T_A=25^\circ C$, unless otherwise specified)

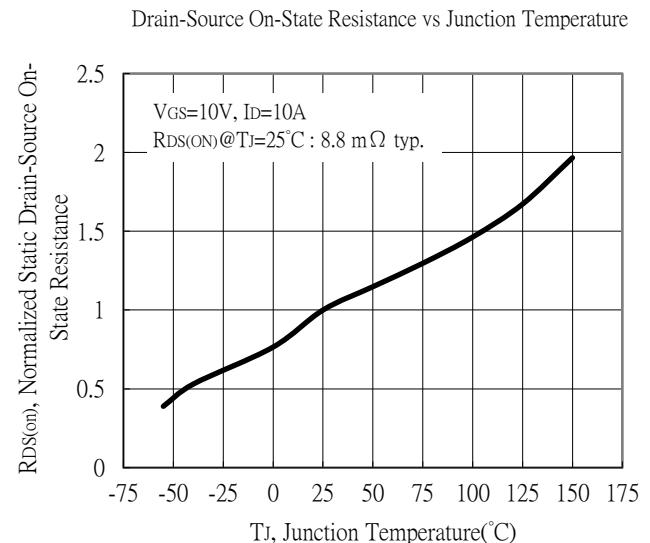
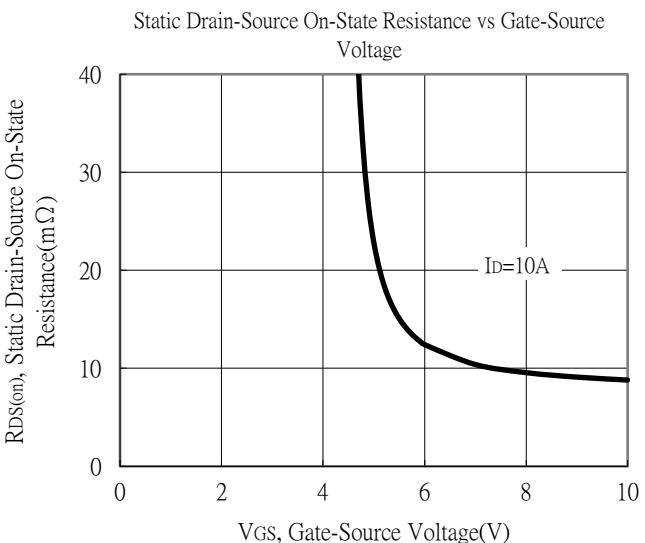
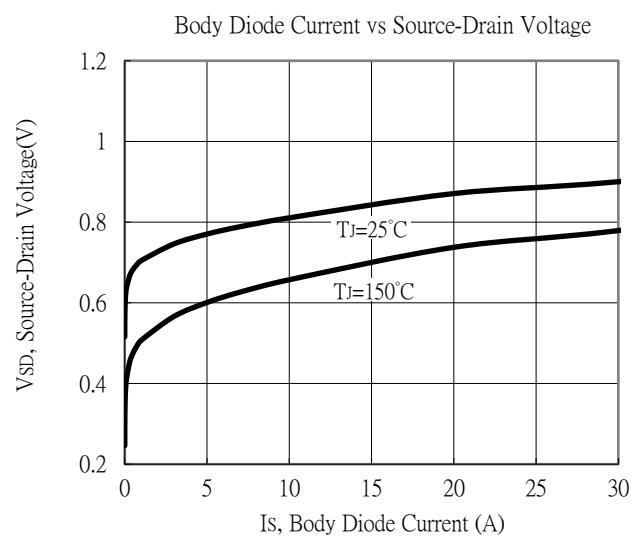
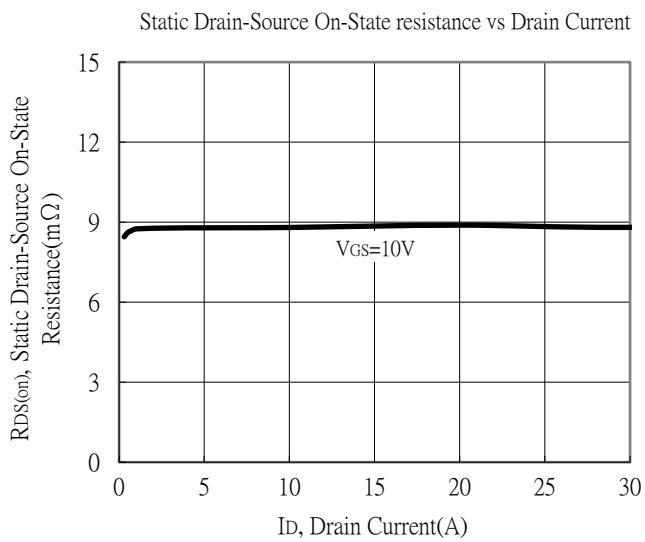
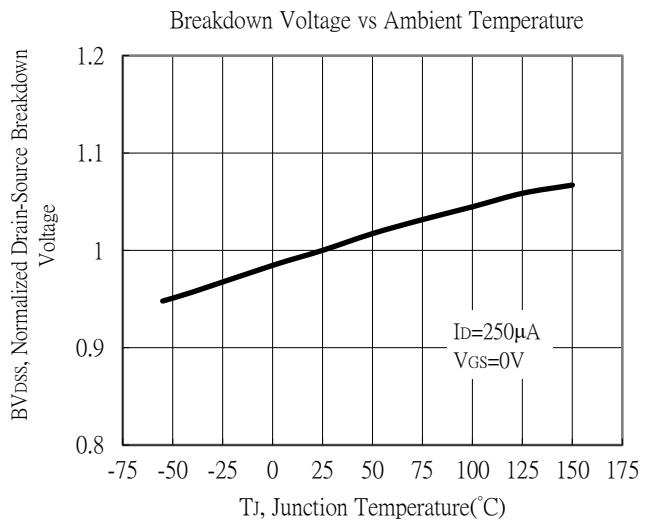
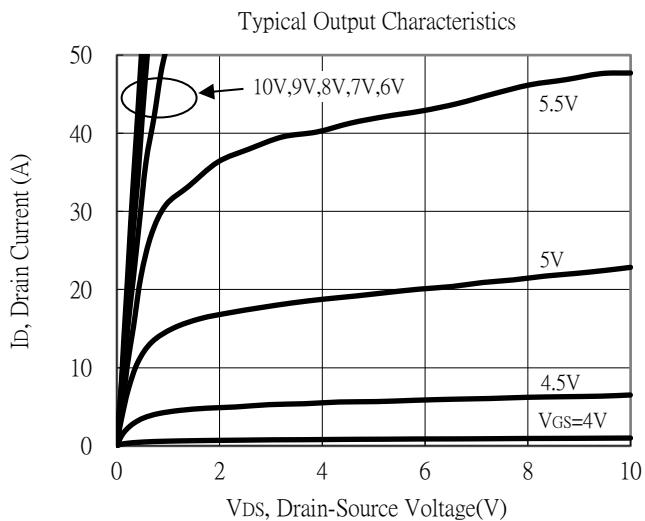
Symbol	Min.	Typ.	Max.	Unit	Test Conditions	
Static						
BV _{DSS}	100	-	-	V	V _{GS} =0V, I _D =250μA	
V _{GS(th)}	2	-	4		V _{DS} =V _{GS} , I _D =250μA	
G _{FS}	-	18	-	S	V _{DS} =5V, I _D =10A	
I _{GSS}	-	-	±100	nA	V _{GS} =±20V, V _{DS} =0V	
I _{DSS}	-	-	1	μA	V _{DS} =80V, V _{GS} =0V	
R _{DSS(ON)}	-	8.8	11.5	mΩ	V _{GS} =10V, I _D =10A	
Dynamic						
C _{iss}	-	1970	-	pF	V _{DS} =50V, V _{GS} =0V, f=1MHz	
C _{oss}	-	305	-			
C _{rss}	-	22	-			
R _g	-	0.6	-	Ω	f=1MHz	
Q _g *1, 2	-	30	-	nC	V _{DS} =50V, I _D =10A, V _{GS} =10V	
Q _{gs} *1, 2	-	9	-			
Q _{gd} *1, 2	-	6.5	-			
t _{d(ON)} *1, 2	-	21	-	ns	V _{DS} =50V, I _D =10A, V _{GS} =10V, R _{GS} =1Ω	
t _r *1, 2	-	17	-			
t _{d(OFF)} *1, 2	-	37	-			
t _f *1, 2	-	8.4	-			
Source-Drain Diode						
V _{SD} *1	-	0.8	1.2	V	I _S =10A, V _{GS} =0V	
t _{rr}	-	37	-	ns	I _F =10A, dI _F /dt=100A/μs	
Q _{rr}	-	48	-	nC		

Note:

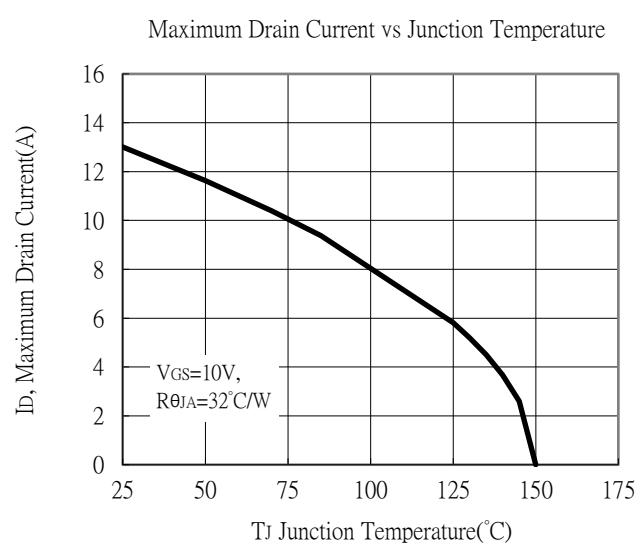
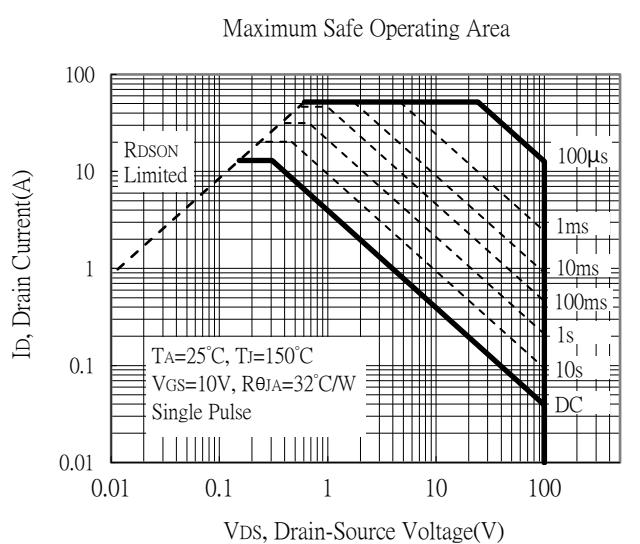
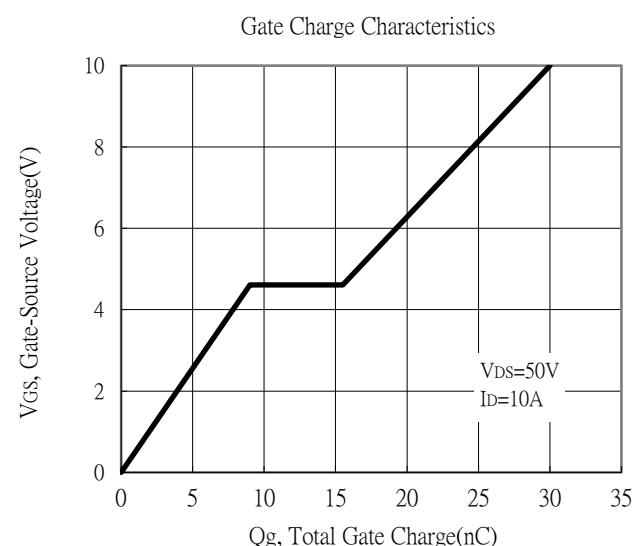
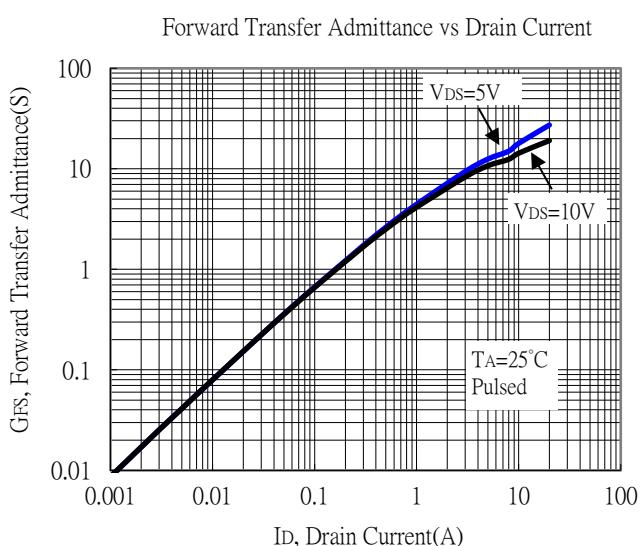
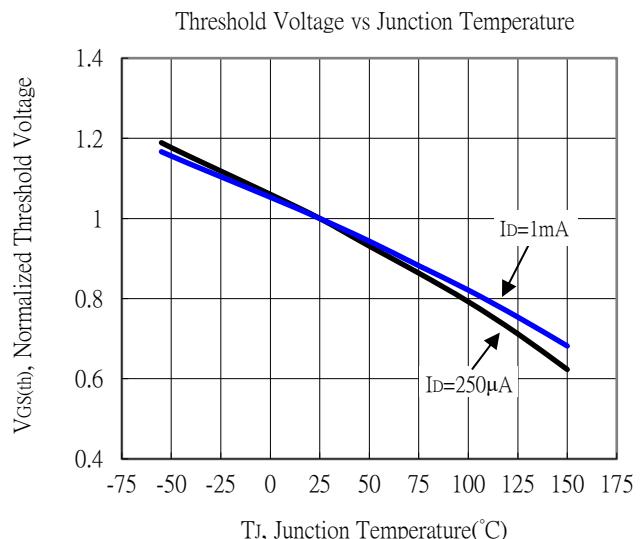
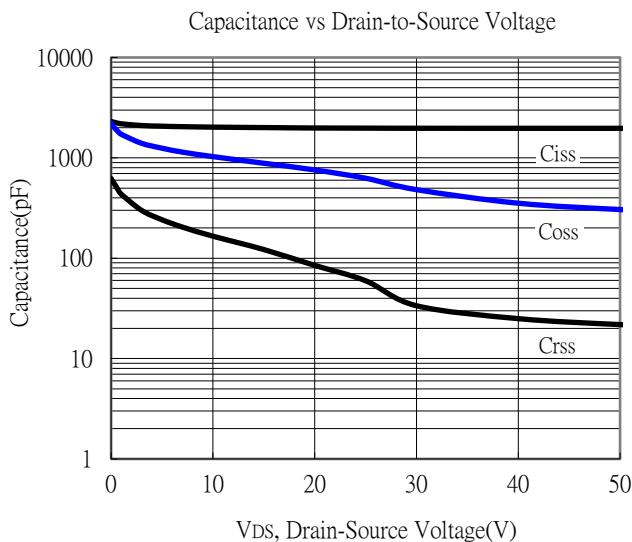
*1. Pulse Test : Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$

*2. Independent of operating temperature

Typical Characteristics

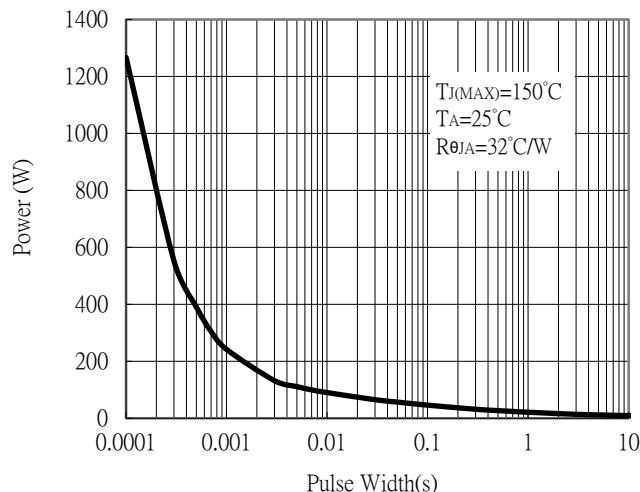


Typical Characteristics (Cont.)

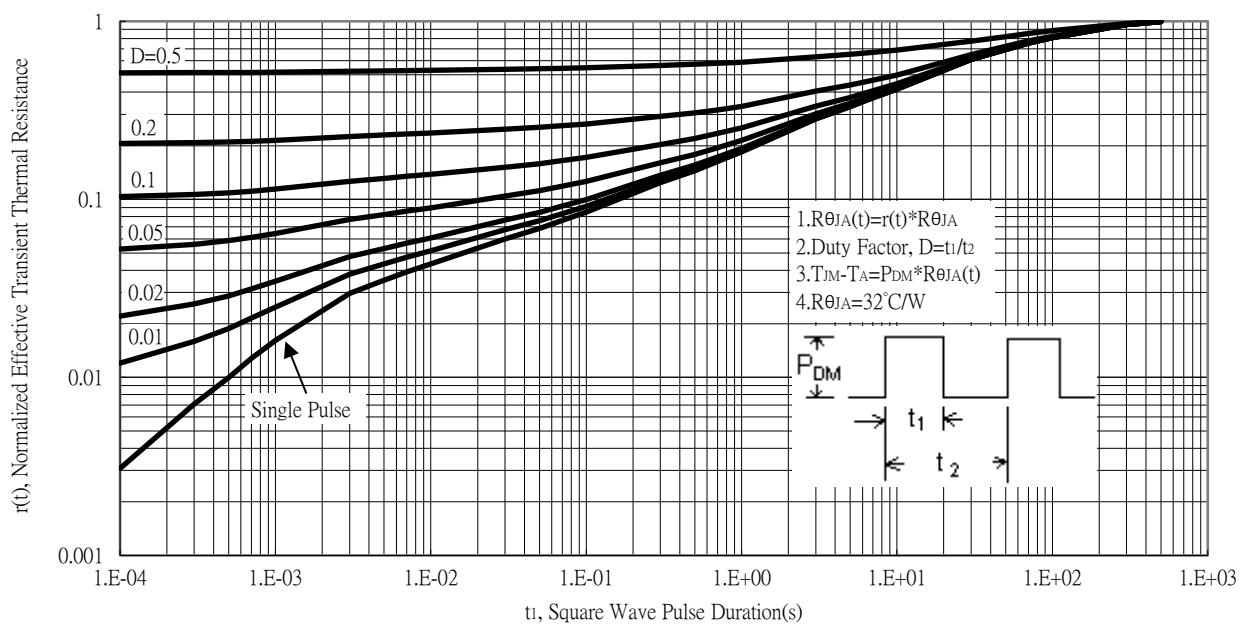


Typical Characteristics (Cont.)

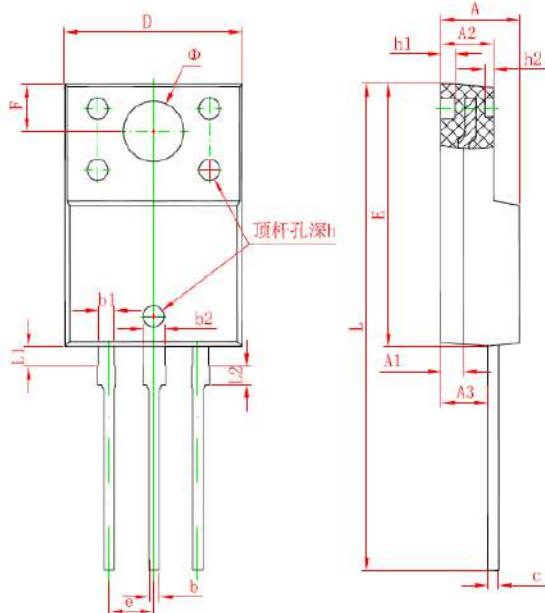
Single Pulse Power Rating, Junction to Ambient



Transient Thermal Response Curves

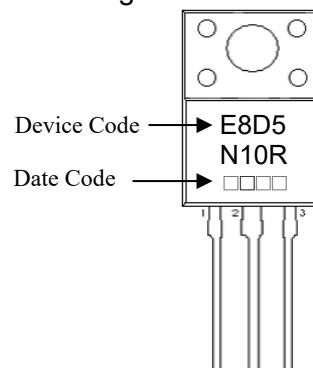


TO-220FP Dimension



3-Lead TO-220FP Plastic Package

Marking:



Style: Pin 1.Gate 2.Drain 3.Source

Date Code(counting from left to right) :

1st code: year code, the last digit of Christian year
 2nd code : month code, Jan→A, Feb→B, Mar→C,

Apr→D, May→E, Jun→F, Jul→G, Aug→H,
 Sep→J, Oct→K, Nov→L, Dec→M

3rd and 4th codes : production serial number, 01~99

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.169	0.185	4.35	4.65	e	0.100 TYP		2.54 TYP	
A1	0.051 REF		1.300 REF		F	0.106 REF		2.70 REF	
A2	0.112	0.124	2.85	3.15	Φ	0.138 REF		3.50 REF	
A3	0.102	0.110	2.60	2.80	h	0.000	0.012	0.00	0.30
b	0.020	0.030	0.50	0.75	h1	0.031 REF		0.80 REF	
b1	0.031	0.041	0.80	1.05	h2	0.020 REF		0.50 REF	
b2	0.043	0.053	1.10	1.35	L	1.102	1.118	28.00	28.40
c	0.020	0.030	0.50	0.75	L1	0.043	0.051	1.10	1.30
D	0.392	0.408	9.96	10.36	L2	0.036	0.043	0.92	1.08
E	0.583	0.598	14.80	15.20					